LA4168M



Record/Playback System for Microcassette and Compact Cassette Recorders

Overview

The LA4168M is a record/playback system IC for microcassette and compact cassette recorders. The LA4168M is an extremely high-functionality IC that includes a motor control governor circuit, a voice sensor circuit that detects sounds and turns motor on or off, a power switch control circuit that receives an electrical signal from a photosensor and turns all of the IC function blocks on or off, and a circuit that increases the speed of the motor during playback.

Functions

- · Microphone and playback preamplifiers
- Record amplifier
- Power amplifier (BTL, 4 Ω)
- Automatic stop circuit (power switch)
- Governor circuit
- · Motor speed and high-speed switching circuit
- Microphone power supply
- LED drive circuit
- · Voice sensor circuit

Features

- Includes a voice switch that can turn the governor on or off.
- Includes a power switch circuit that can turn all the IC function blocks on or off from a photosensor signal. During record, the IC can automatically turn the governor on or off according to the microphone input level, and furthermore, the governor on/off level can be continuously adjusted from an external control knob. (The control used for volume adjustment during playback.)
- Continuously variable microphone monitor level.
- Includes a drive pin for an LED that lights only when the governor is on in record mode.

Package Dimensions

unit: mm

3073A-MFP30SD



Specifications

Maximum	Ratings	at Ta =	25°C
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Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		4.5	V
Allowable power dissipation	Pd max		800	mW
Operating temperature	Topr		-10 to +50	°C
Storage temperature	Tstg		-55 to +150	°C

Operating Conditions at $Ta = 25^{\circ}C$

Parameter		Symbol	Conditions	Ratings	Unit
Recommended	supply voltage	V _{CC}		3.0	V
Operating voltag	je range	V _{CC} op		1.8 to 3.6	V
Load resistance	(power block)	R _L pwr		4	Ω
	(preamplifier block)	R _L pre		10	kΩ

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Operating Characteristics at Ta = 25°C, V_{CC} = 3.0 V, R_L = 4 Ω (power amplifier), R_L = 10 k Ω (preamplifier), f = 1 kHz, 0 dBm = 0.775 V

			Ratings			Linit	
	Symbol	Conditions	min	typ	max	Unit	
[PRE + POWER + GVN]	[PRE + POWER + GVN]						
Standby current	I _{STB}	With pin 9 connected to V _{CC} through a 100-kΩ resistor	25	170	250	μA	
[PRE + POWER]		· · ·		н			
Quiescent current	I _{CC-R}		6	12	18	mA mA	
Voltage gain	VGTP	PLAY MODE, $VI = 0.0$, VOL MIN PLAY MODE, $V_0 = -5 \text{ dBm}$	71.5	74	25 76.5	dB	
[EQ AMP]						<u> </u>	
Voltage gain (open loop)	VG _{OP}	C _{NF} = 100 μF	80	85		dB	
Voltage gain (closed loop)	VGP		50	52	54	dB	
Maximum output voltage	V _{OP} max	THD = 1 %	0.5	0.75		V	
I otal harmonic distortion	IHD _P	$V_0 = 0.3 V$		0.2	0.6	%	
Ripple rejection ratio	VNIP R	$Rg = 2.2 k\Omega f_{D} = 1 kHz filter$	45	60	2.0	μv dB	
IMIC AMPI VOL MIN. ALC OFF	Гтр	$Rg = 2.2 Rs_2, R = 1 Rr 12 Rr 101$	-10	00			
Voltage gain (closed loop)	VG _M 1	ALC OFF	43	45	47	dB	
Maximum output voltage	VOmaxM	THD = 1 %, R _L = 10 kΩ	0.5	0.75		V	
Total harmonic distortion	THD _M	V _O = 0.3 V		0.6	1.0	%	
Equivalent input noise voltage	V _{NIM}	$Rg = 3 k\Omega$, DIN audio		2.0	4.0	μV	
Ripple rejection ratio	SVRR	$Rg = 3 k\Omega, f_R = 1 kHz filter$	40	53	40	dB	
	I KIM	1	24	32	40	K22	
Voltage gain (closed loop)	VGRT	ALC OFF	63.5	65.5	67.5	dB	
Maximum output voltage	VOmaxR	THD = 5 %	0.6	1.0	0110	V	
Output noise voltage	VNORT	MIC Input, Rg = $3 k\Omega$, DIN audio		3.5	8.0	mV	
Ripple rejection ratio	R _{rRT}	$Rg = 3 k\Omega$, $f_R = 1 kHz$, 1 kHz filter	20	32		dB	
[POWER AMP]		1					
Voltage gain (closed loop)	VG _{BTL}	BTL ON, $V_0 = -10 \text{ dBm}$	21.5	24	26.5	dB	
Voltage gain (closed loop)	VG _{SIN}	Single, $V_0 = -10 \text{ dBm}$	20.5	23	25.5	dB	
Output power	POBTL	IHD = 10 %, BIL ON	200	350		mvv m\//	
Total harmonic distortion		HD = 10%, Single	0.1	0.8	2	111VV %	
Output noise voltage	VNORTI	BTLON Rg = 0.23 V	0.1	20	50	70 UV	
Ripple rejection ratio	RrBTI	BTL ON, Rg = 0 kΩ, f_R = 1 kHz , 1 kHz filter	50	70	00	dB	
Output DC offset	VDCOFF	BTL ON, Rg = $0 k\Omega$	0	10	50	mV	
Input resistance	RINBTL		21	30	39	kΩ	
[ALC]							
ALC width	ALC _W	The input level width from the point the ALC circuit operates to the point the harmonic distortion reaches 5%	40	67		dB	
ALC harmonic distortion	ALC _{THD}	Vim = -40 dBm		1.0	2.0	%	
ALC output	ALC Vo	Vim = -40 dBm	0.33	0.43	0.53	V	
ALC start input	ALC V _{IN}	Vim = -40 dBm	-79	-74	-69	dBm	
[Voice Sensor (VOX)]	Van	VOLUME (10 kO) max	_90	_85	_80	dBm	
			-30	-05	-00	dB	
[Auto-Stop]	1 ·O HL		, v	Ŭ			
Operation voltage	V _{I ATS}	The pin 9 voltage at the point the auto-stop circuit operates	0.65	0.7		V	
[LED]		·	·				
LED drive current	I _{LED}	The input current when shorted through a $300-\Omega$ resistor	8	15	22	mA	
[GVN]		·					
Reference voltage	Vref	Im = 100 mA	1.1	1.25	1.4	V	
Current division ratio	K	Im = 50 - 100 mA	45	50	55		
Residual voltage	Vsat	V _{REF} = CONT, Im = 200mA	0.1	0.2	0.5	V	
The CONT pin voltage in speed up mode	VCONT		0.35	0.41	0.47	V	
Reference voltage/voltage characteristics	Vref /ΔV _{CC}	V _{CC} = 1.8 to 4.5 V, Im = 100 mA	0	0.2	0.6	%/V	
Current division ratio/voltage characteristics	$\frac{\Delta n}{K} / \Delta V_{CC}$	$V_{CC} = 2.0 \text{ to } 4.5 \text{ V}, \text{ Im} = 50 - 100 \text{ mA}$	0	0.3	0.7	%/V	
Reference voltage/current characteristics	$\frac{\Delta \text{Vref}}{\text{Vref}} / \Delta \text{Im}$	Im = 50 – 200 mA	0	0.002	0.03	%/mA	
Current division ratio/current characteristics	$\frac{\Delta K}{Vref}/\Delta Im$	Im = 50 – 100 mA to 150 – 200 mA	-0.07	0.03	+0.07	%/mA	



Block Diagram



Test Circuit Diagram



Sample Application Circuit



For the record/playback switch described above, during playback the power supply ripple may be output from the REC OUT pin (pin 4) and influence the EQIN pin (pin 29). This problem can be minimized by adding a 5.6-k Ω resistor between pin 4 and pin 27.

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